

Numerical Thermal Stress Analysis on Semiconductors with Nano-Fluid Coolant

Luis Medina, Kevin Harvey, Cory Davison, Edgar Rubio, Morteza Mohssenzadeh, Hamidreza Ghasemi , Taha Ghaemi Bahraseman

Received: 28 December 2021 Accepted: 22 January 2022 Published: 2 February 2022

Abstract

During the course of normal operation, electrical components made from semiconducting materials undergo significant stress from heating. This causes parts to wear out more quickly or, in the more extreme cases, fail altogether. In order to maintain a stable operating temperature, many different types of cooling systems have been used. Our work investigates the best materials to use in these systems, carefully considering effectiveness, cost, and longevity in our assessment. Ansys simulation software was used to simulate the effects of different coolants on removing heat from a semiconductor. The coolants are air, water, and aluminum oxide. Though we didn't model the results of forced convection across these materials, the natural convection heat transfer results in finding the more efficient coolant. Considering liquid cooling methods for semiconductor-based devices, the kind of fluid plays a vital role in the transfer of energy. The Aluminum Oxide was selected in a 2

Index terms— thermal stress, nano-fluid aluminum oxide coolant, semiconductors.

1 I. Introduction

Because many of these components can only work properly within a relatively narrow temperature range, an entire industry has materialized that is dedicated to keeping them cool [1]. Consequently, a great deal of time and money has been spent researching the best materials for transferring energy from the delicate components and releasing it into another medium [2]. We entered this project with the goal of finding the most suitable materials for cooling semiconductor-based electrical components like CPUs. The two types of cooling methods examined are the use of heat sinks and pumped liquid cooling.

First, we examine cooling systems using heat sinks. Heat sinks transfer heat from the component via conduction and release that heat in the surrounding air through both convection and radiation. The primary factor in determining the effectiveness of a material for this process is its thermal conductivity, though thermal diffusivity is also a major factor [3]. The former determines the material's ability to transfer heat away from the source while the latter speaks to its ability to move the energy throughout itself, as well as radiate it away. Usually, heat sinks are used in a forced convection system with air being moved across the heat sink fin [4]. We examined several materials for this section and have arranged them within Table_1. Aluminum, reminiscent of aluminum and a thermal conductivity comparable to the much heavier copper, CarbAl provides the best attributes of both materials. Its thermal diffusivity is also significantly higher than the others, allowing for better energy flux throughout itself. This material was designed in 2008 by Applied Nanotech Inc. and remains a superior material for many applications, including heat sinks for high end applications.

2 II. Nanofluid Simulation

With regards to liquid cooling systems for semiconductor-based devices, the type of fluid plays a significant role in the transfer of energy. We selected Aluminum Oxide in a 2% solution and 40nm wide particles to simulate for our nanofluid as it is commonly used in the industry and data for it was readily available [7] [8]. The

43 properties of the Materials used (simulated) in this study are provided in tables 2, 3 and 4. Borondoped silicon
44 and phosphorus-doped silicon, Air, Water, Aluminum oxide nanoparticles for nanofluid.

45 3 Analysis Setup & Methodology

46 Simulation was done using convection to transfer heat from SM to cooling fluid. Convective heat transfer
47 coefficient (h_c) was used the principal property of fluid for simulation.

48 We found that this coefficient depended type of medium such as gas or liquid, flow properties such as velocity,
49 viscosity and other flow and temperature dependent properties [8].

50 Many of the research papers we found used other values and coefficients that are the norm in the field of
51 thermodynamics. Nusselt, Rayleigh, and Reynolds numbers were discussed in these papers, however, since these
52 are out of the scope of this class, we decided to use convection [12][13][14]. The terms stated above do depend
53 on convection so it's not as to completely ignore the experimental results from researchers; convection allowed
54 us to simplify our model.

55 4 Global Journal of Researches in

56 5 ANSYS

57 Main purpose was to compare the cooling capabilities of air, water, and nanofluids by forced convection. Finding
58 comparable values for the heat transfer coefficients (HTC) of each of these values was a problem, mainly because
59 it was difficult to find experimental results that had been performed under the same conditions [12][13][14][15].
60 However, we were able to find papers that contained the information for water and aluminum oxide nanofluids
61 although there were calculations needed as well as estimating values from graphs demonstrating results. These
62 papers contained the needed coefficients for water and Al-Ox under similar conditions such as mass flow (1.5
63 liters per minute) and temperature (40?) therefore we could use comparable values for their respective HTC's
64 [7,8].

65 A simplified geometry was used in the simulation. The actual geometry of a transistor (our example for
66 semiconductor) was convoluted. In addition, the electronic components had to be omitted from the modeling
67 because the focus was on thermal impact and because it was simpler to declare one region of the geometry as
68 the heat source. Another simplification had to do with energy bands, to understand and model such concept, an
69 understanding of Fermi function, Fermi-Dirac distribution, Boltzmann approximation, and electron concentration
70 under different temperature conditions [12][13][14][15].

71 What we expected to see in the ANSYS Fluent heat maps was the heat dissipated from the source out through
72 the boundaries making contact with the fluid. However, this was not the case the first few times that we ran the
73 simulation. This was due to the geometry of our model; we had placed one geometry meant to represent the fluid
74 above the geometry representing the semiconductor. There was an issue with the boundary where the surfaces
75 met and thus, we decided to change our approach by convection.

76 Once we read up on how convection worked, we could set up our model an analogous fashion [5]. This resulted
77 in a simpler model where only a single geometry was needed which was meant to represent the semiconductor.

78 Using ANSYS Fluent, the mesh was imported and given three different boundaries. The bottom edge along
79 with both vertical edges were all labeled "outlet boundary" meaning these edges were to make contact with
80 our test fluids (air, water, nanofluid). The top edge was the heat source; it was meant to be analogous to the
81 conduction band on a transistor although in reality the situation is complex [15]. The surface of the body was
82 the third boundary and this is where the properties of a semiconductor were applied to. A nanofluid composed
83 of 98% water and 2% aluminum oxide (of particle size 40nm) showed significant improvement (Figure ??) in the
84 rate of heat transfer over water (Figure ??) and air (Figure 1). Faiza Nazir's results showed a 200% improvement
85 over water's rate of heat transfer [7].

86 6 IV. Results

87 7 V. Discussion

88 According to a handful of the research papers and experimental reports, the principal variables that accounted for
89 the nanofluid's superior performance included: intensification of turbulence or eddy, suppression or interruption
90 of the boundary layer as well as dispersion or back mixing of the suspended Global Journal of Researches in
91 Engineering (A) Volume Xx XII Issue II V ersion I nanoparticles, in addition to the nanoparticles' thermal
92 conductivity and heat capacity [12].

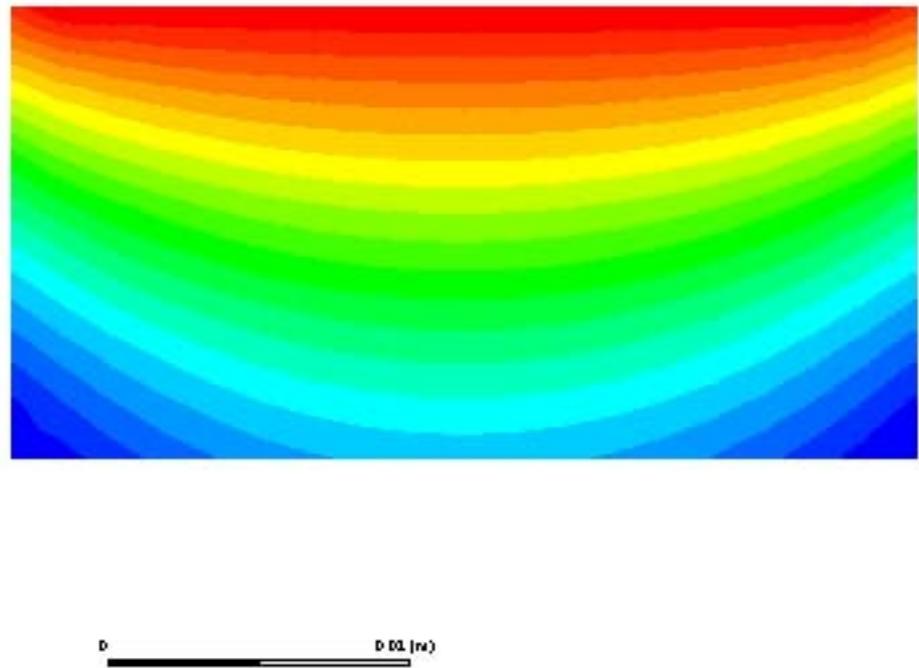
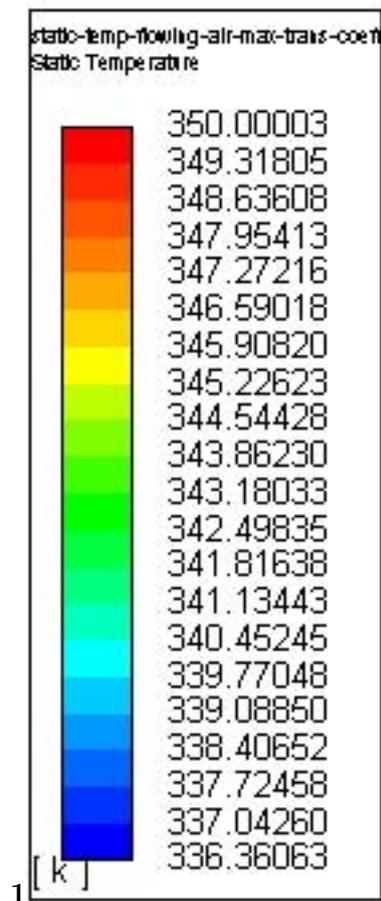
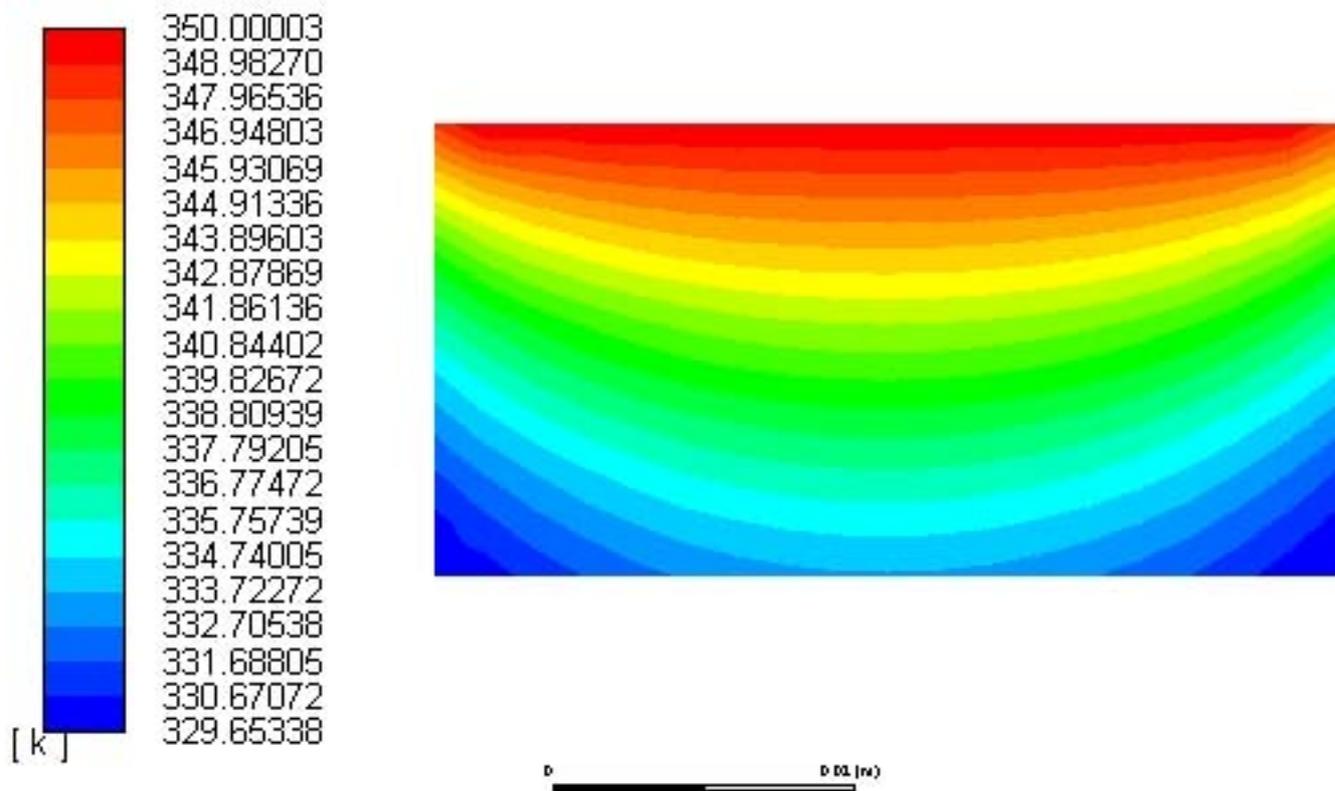


Figure 1: Figure 1 :

static-temp-flowing-0-0-0-celsius-1.5pm
 Static Temperature



23

Figure 2: Figure 2 :Figure 3 :

1

Year 2022

21

(A) Volume Xx XII Issue II V ersion I

Global Journal of Researches in Engineering

[Note: USA. e-mail: hghasemi@sdccd.edu Author ? : Mechanical Engineering Department, Shahid Beheshti University, Tehran, Iran.]

Figure 3: Table 1 :

2

Figure 4: Table 2 :

3

Figure 5: Table 3 :

Figure 6: Table 4 :

93 **8 VI. Conclusion**

94 The Al₃O₂ (40nm @ 2% volume) nanofluid had the best cooling performance of the three tested materials.
95 ^{1 2}

¹Year 2022 © 2022 Global Journals Numerical Thermal Stress Analysis on Semiconductors with Nano-Fluid Coolant

²© 2022 Global Journals Numerical Thermal Stress Analysis on Semiconductors with Nano-Fluid Coolant

-
- 96 [National Advisory Committee for Aeronautics Report] , [https://ntrs.nasa.gov/search.jsp?R=](https://ntrs.nasa.gov/search.jsp?R=19930092197)
97 **19930092197** *National Advisory Committee for Aeronautics Report* 1170.
- 98 [Journal of Applied Physics ()] , 10.1063/1.1458057. <https://doi.org/10.1063/1.1458057> *Journal of*
99 *Applied Physics* 2002. 91 p. 5079.
- 100 [Aghayari et al. ()] ‘Aluminum Oxide Nanofluid Energy Transfer’. R Aghayari , H Maddah , Z Sharifnezhad , A
101 Hakiminejad , S Sarli . 10.7508/tpnms.2015.01.006. *Transp Phenom Nano Micro Scales* 2015. 3 (1) p. .
- 102 [William J. Vigrass (ed.)] *Calculation of Semiconductor Failure Rates by*, [http://docplayer.net/](http://docplayer.net/29883772-Calculation-of-semiconductor-failure-rates.html)
103 **29883772-Calculation-of-semiconductor-failure-rates.html** William J. Vigrass (ed.)
- 104 [Sharma Hisham Hamid] ‘Engineering Applications of Nanotechnology’. 10.1007/978-3-319-29761-3_2. *Topics in*
105 *Mining, Metallurgy and Materials Engineering*, K, Viswanatha Sharma, N Hisham, Hamid (ed.)
- 106 [Adnan et al. ()] ‘Experimental Measurements of Nanofluids Thermal Properties’. M Adnan , R A Husein , K
107 Bakar , K V Kadirgama , Sharma . *International Journal of Automotive and Mechanical Engineering* 1985-
108 9325. 2013. Online. 7 p. . (Print)
- 109 [Nasir ()] ‘Heat Transfer of Aluminium-Oxide Nanofluids in a Compact Heat Exchanger’. F M Nasir . *Applied*
110 *Mechanics and Materials, Vols*, 2014. p. .
- 111 [Inc Silicon Oxide Spherical Powder] *Inc Silicon Oxide Spherical Powder*, [https://www.usnano.com/inc/](https://www.usnano.com/inc/sdetail/46881)
112 **sdetail/46881** 0 p. . US Research Nanomaterials
- 113 [Xuan and Li ()] *Investigation on Convective Heat Transfer and Flow Features of Nanofluids*, Yimin & Xuan
114 , Qiang Li . 125. 10.1115/1. 1532008. 2003. (Journal of Heat Transfer-transactions of The Asme -J HEAT
115 TRANSFER)
- 116 [SkySpring Nanomaterials Tin Oxide Nanoparticles] *SkySpring Nanomaterials Tin Oxide Nanoparticles*,
117 https://ssnano.com/inc/sdetail/tin_oxide_nanoparticles/235 0 p. .
- 118 [Thermal Conductivity of common Materials and Gases] [https://www.engineeringtoolbox.com/](https://www.engineeringtoolbox.com/thermal-conductivity-d_429.html)
119 **thermal-conductivity-d_429.html** *Thermal Conductivity of common Materials and Gases*,